

**AXIAL LEADED HERMETICALLY SEALED
 SUPERFAST RECTIFIER DIODE**
**QUICK
 REFERENCE DATA**

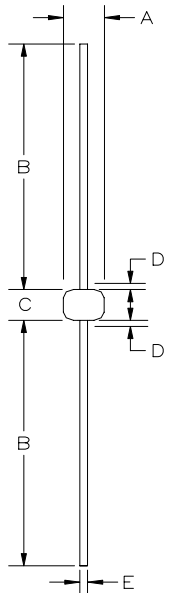
- Very low reverse recovery time
- Hermetical sealed in Metoxillite fused metal oxide
- Low switching losses
- Soft, non-snap off, recovery characteristics
- Very low forward voltage drop

- $V_R = 50 - 150V$
- $I_F = 6.0A$
- $t_{rr} = 30ns$
- $I_R = 5\mu A$

ABSOLUTE MAXIMUM RATINGS (@ 25°C unless otherwise specified)

	Symbol	1N5807	1N5809	1N5811	Unit
Working reverse voltage	VRWM	50	100	150	V
Repetitive reverse voltage	VRRM	50	100	150	V
Average forward current (@ 75°C, lead length = 0.375")	IF(AV)	←———— 6.0 —————→			A
Repetitive surge current (@ 55°C in free air, lead length 0.375")	IFRM	←———— 25 —————→			A
Non-repetitive surge current (tp = 8.3mS, @ VR & Tjmax)	IFSM	←———— 125 —————→			A
Storage temperature range	TSTG	←———— -65 to +200 —————→			°C
Operating temperature range	TOP	←———— -65 to +175 —————→			°C

MECHANICAL



G112

Dimensions					
DIM ^N	Millimeters		Inches		Note
	MIN	MAX	MIN	MAX	
A	2.92	3.61	.115	0.142	-
B	22.9	33.0	0.90	1.30	-
C	3.3	7.62	.130	0.3	-
D	-	0.80	-	.030	1
E	0.91	1.07	0.036	.042	-

Note:
(1) Lead diameter uncontrolled over this region.

Weight = 0.013oz

These products are qualified to MIL-PRF-19500/477 and are preferred parts as listed in MIL-STD-701. They can be supplied fully released as JANTX, JANTXV, and JANS versions

ELECTRICAL CHARACTERISTICS (@ 25°C unless otherwise specified)

	Symbol	1N5807	1N5809	1N5811	Unit
Average forward current max. (pcb mounted; $T_A = 55^\circ\text{C}$) for sine wave	$I_{F(AV)}$	← 1.7 →	← 1.7 →	← 1.7 →	A
	$I_{F(AV)}$	← 1.8 →	← 1.8 →	← 1.8 →	A
Average forward current max. ($T_L = 55^\circ\text{C}$; $L = 3/8''$) for sine wave	$I_{F(AV)}$	← 5.7 →	← 5.7 →	← 5.7 →	A
	$I_{F(AV)}$	← 6.0 →	← 6.0 →	← 6.0 →	A
I^2t for fusing ($t = 8.3\text{mS}$) max.	I^2t	← 32 →	← 32 →	← 32 →	A ² S
Forward voltage drop max. @ $I_F = 4.0\text{A}$, $T_j = 25^\circ\text{C}$	V_F	← 0.875 →	← 0.875 →	← 0.875 →	V
Reverse current max. @ V_{RWM} , $T_j = 25^\circ\text{C}$ @ V_{RWM} , $T_j = 100^\circ\text{C}$	I_R	← 5.0 →	← 5.0 →	← 5.0 →	μA
	I_R	← 150 →	← 150 →	← 150 →	μA
Reverse recovery time max. 1.0A I_F to 1.0A I_R . Recovers to 0.1A I_{RR} .	t_{rr}	← 30 →	← 30 →	← 30 →	nS
Junction capacitance typ. @ $V_R = 5\text{V}$, $f = 1\text{MHz}$	C_j	← 60 →	← 60 →	← 60 →	ρF

THERMAL CHARACTERISTICS

	Symbol	1N5807	1N5809	1N5811	Unit
Thermal resistance - junction to lead Lead length = 0.75"	$R_{\theta JL}$	← 22 →	← 22 →	← 22 →	°C/W
Thermal resistance - junction to amb. on 0.06" thick pcb. 1 oz. copper.	$R_{\theta JA}$	← 90 →	← 90 →	← 90 →	°C/W

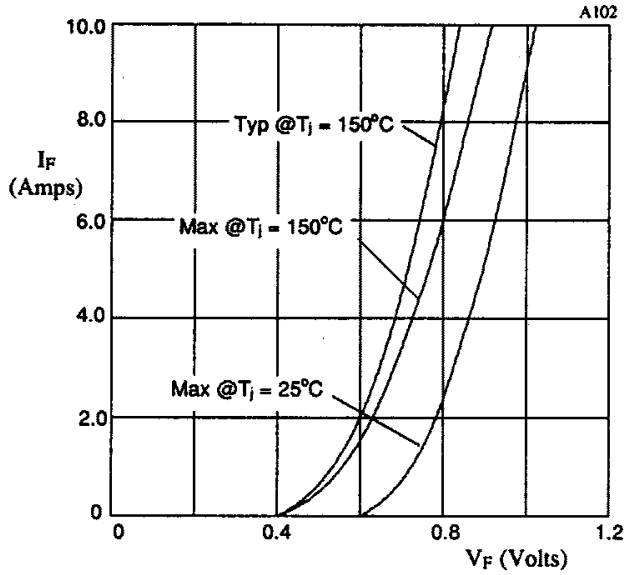


Fig 1. Forward voltage drop as a function of forward current.

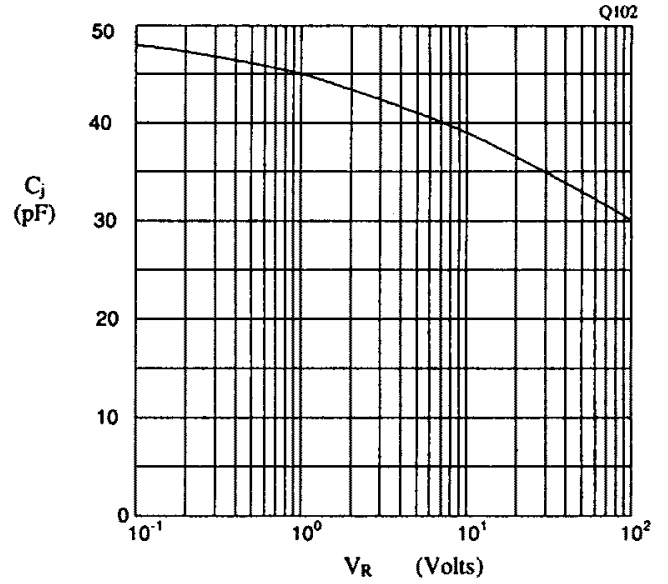


Fig 2. Typical junction capacitance as a function of reverse voltage.